Product data sheet

1. General description

Ultrafast power diode in a 2-lead TO263 plastic package





2. Features and benefits

- Fast switching
- Low leakage current
- · Low reverse recovery current
- · Low thermal resistance
- · Reduces switching losses in associated MOSFET or IGBT

3. Applications

- · Active PFC in air conditioner
- · High frequency switched-mode power supplies
- Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values		Unit			
Absolute maximum rating									
V_{RRM}	repetitive peak reverse voltage			650			V		
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 135$ °C; Fig. 1; Fig. 2; Fig. 3		8		А			
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 135 °C; square-wave pulse		16		А			
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		95		А			
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		104.5		Α			
Symbol	Parameter	Conditions	Notes	Min Typ Max		Unit			
Static ch	aracteristics								
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		- 1.37 1.70		1.70	V		
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.13	1.46	V		
Dynamic characteristics									
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	27	-	ns		

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	nc	no connected		K 14 A
2	K	cathode [1]		K -
3	А	anode		
mb	mb	mounting base; connected to cathod		

^[1] It is not possible to connect to pin 2 of the TO-263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV8MB-650P	TO263	BYV8MB-650PJ	Reel	800	TO263d	17-Mar-2023

7. Marking

Table 4. Marking codes

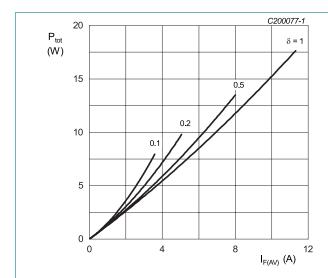
Type number	Marking codes
BYV8MB-650P	BYV8MB 650P

8. Limiting values

Table 5. Limiting values

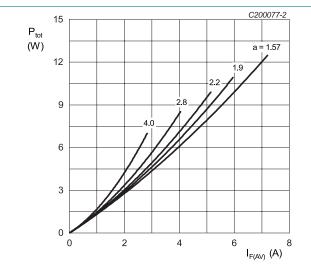
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 135 °C; Fig. 1; Fig. 2; Fig. 3		8	А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 135 °C; square-wave pulse		16	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		95	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		104.5	Α
T _{stg}	storage temperature			-65 to 175	°C
T _j	junction temperature			-65 to 175	°C



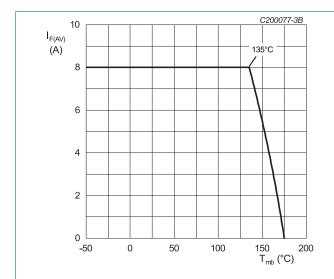
 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_0 = 1.255 \text{ V}; R_s = 0.0270 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.255 V; R_s = 0.0270 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





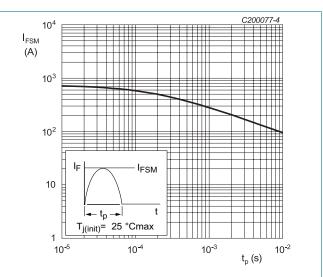


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	2.95	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

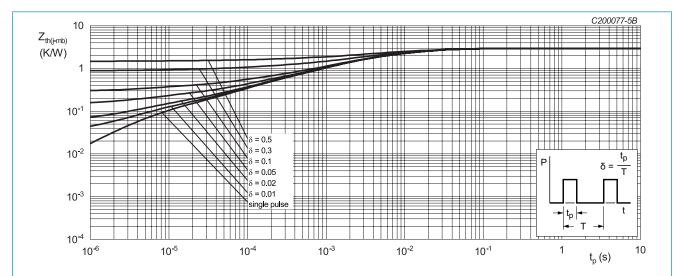
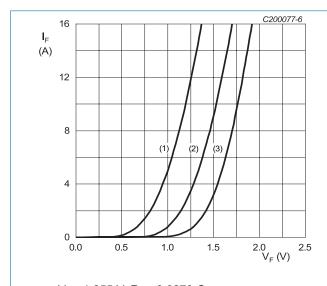


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.37	1.70	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.13	1.46	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C		-	0.27	30	μA
		V _R = 650 V; T _j = 150 °C		-	-	0.5	mA
Dynamic	characteristics						
Q _r	reverse charge	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	151	-	nC
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	360	-	nC
t _{rr}	reverse recovery time	$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{rr} = 0.25 \text{ A}; T_j = 25 \text{ °C}$		-	30	-	ns
		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	27	-	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	56	-	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	85	-	ns
I _{RM}	peak reverse recovery current	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	5.5	-	А
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	8.6	-	А
E _{as}	non-repetitive avalanche energy	T _{j(init)} = 25 °C		20	-	-	mJ



 V_o = 1.255 V; R_s = 0.0270 Ω

(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values (3) $T_j = 25$ °C; maximum values



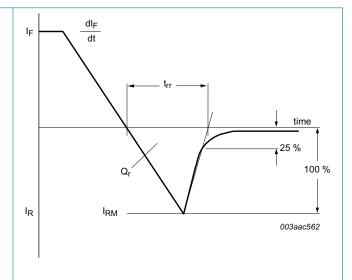
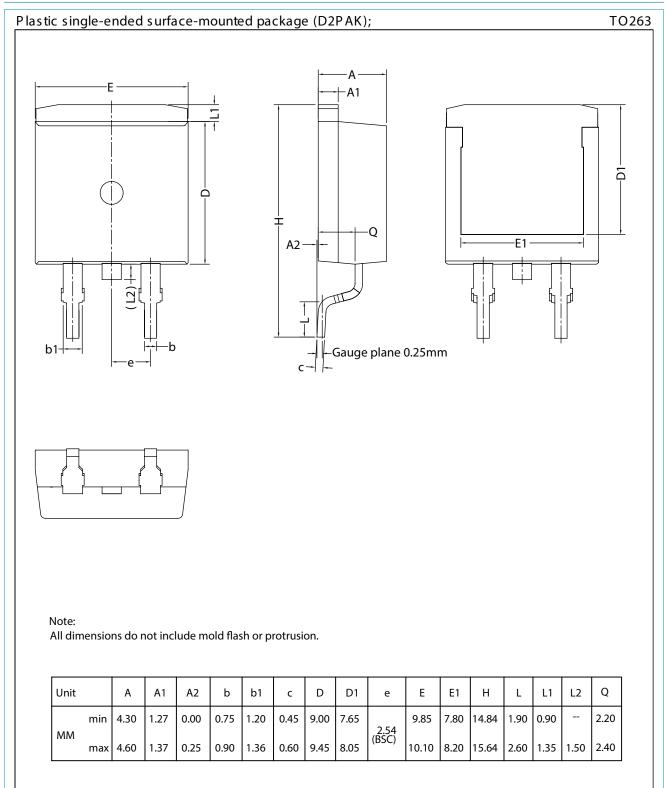


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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